W005M THRU W10M

SILICON BRIDGE RECTIFIERS Reverse Voltage – 50 to 1000 V Forward Current – 1.5 A

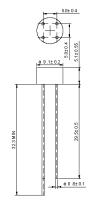
Features

- Rating to 1000 V PRV
- Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- Glass passivated chip junction

Mechanical Data

Case: WOB, Molded plasticPolarity: As marked on Body

WOB



Dimensions in millimeters

Absolute Maximum Ratings and Characteristics

Ratings at $25\,^{\circ}$ C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	W005M	W01M	W02M	W04M	W06M	W80W	W10M	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Output Current at $T_C = 50$ °C	I _{F(AV)}	1.5							А
Peak Forward Surge Current, 8.3 ms Single Half- Sine-Wave Superimposed on Rated Load (JEDEC Method)	Ігэм	50							А
Maximum Instantanous Forward Voltage at 1 A	V _F	1							V
Maximum Reverse Current $T_A = 25 ^{\circ}\text{C}$ at Rated DC Blocking Voltage $T_A = 125 ^{\circ}\text{C}$	I _R	5 0.5							μA mA
Operating Junction Temperature Range	TJ	- 55 to + 125							°C
Storage Temperature Range	T _{stg}	- 55 to + 150							°C



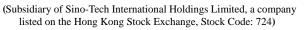




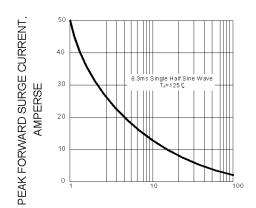






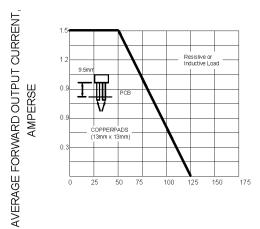


FIG.1 - PEAK FORWARD SURGE CURRENT



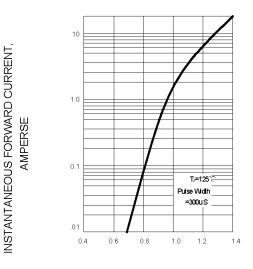
NUMBER OF CYCLES AT 60Hz

FIG.2 - FORWARD DERATING CURVE



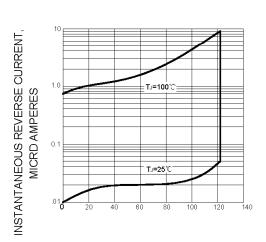
CASE TEMPERATURE, °C

FIG.3 - TYPICAL FORWARD CHARACTERISTIC



INSTANTANEOUS FORWARD VOLTAGE, VOLTS

FIG.4 - TYPICAL REVERSE CHARACTERISTIC



PERCENT OF RATED PEAK REVERSE VOLTAGE



SEMTECH ELECTRONICS LTD.

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